

# DATA SHEET

## 80C652/83C652 CMOS single-chip 8-bit microcontrollers

Product specification  
IC20 Data Handbook

1996 Aug 15

## CMOS single-chip 8-bit microcontrollers

## 80C652/83C652

## DESCRIPTION

The P80C652/83C652 Single-Chip 8-Bit Microcontroller is manufactured in an advanced CMOS process and is a derivative of the 80C51 microcontroller family. The 80C652/83C652 has the same instruction set as the 80C51. Three versions of the derivative exist:

83C652 — 8k bytes mask programmable ROM

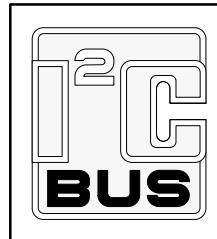
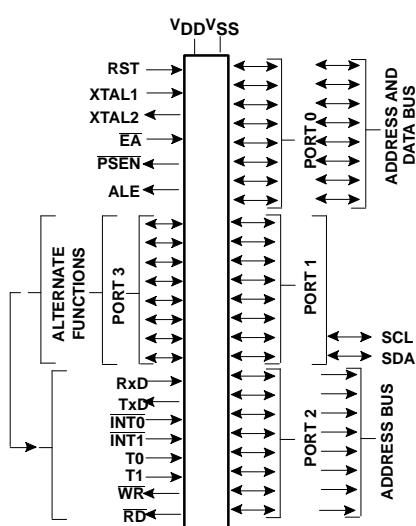
80C652 — ROMless version

87C652 — EPROM version (described in a separate chapter)

This device provides architectural enhancements that make it applicable in a variety of applications for general control systems. The 8XC652 contains a non-volatile 8k × 8 read-only program memory, a volatile 256 × 8 read/write data memory, four 8-bit I/O ports, two 16-bit timer/event counters (identical to the timers of the 80C51), a multi-source, two-priority-level, nested interrupt structure, an I<sup>2</sup>C interface, UART and on-chip oscillator and timing circuits. For systems that require extra capability, the 8XC652 can be expanded using standard TTL compatible memories and logic.

The device also functions as an arithmetic processor having facilities for both binary and BCD arithmetic plus bit-handling capabilities. The instruction set consists of over 100 instructions: 49 one-byte, 45 two-byte and 17 three-byte. With a 16(24)MHz crystal, 58% of the instructions are executed in 0.75(0.5)µs and 40% in 1.5(1)µs. Multiply and divide instructions require 3(2)µs.

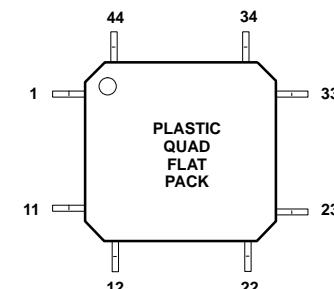
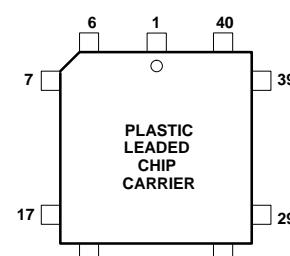
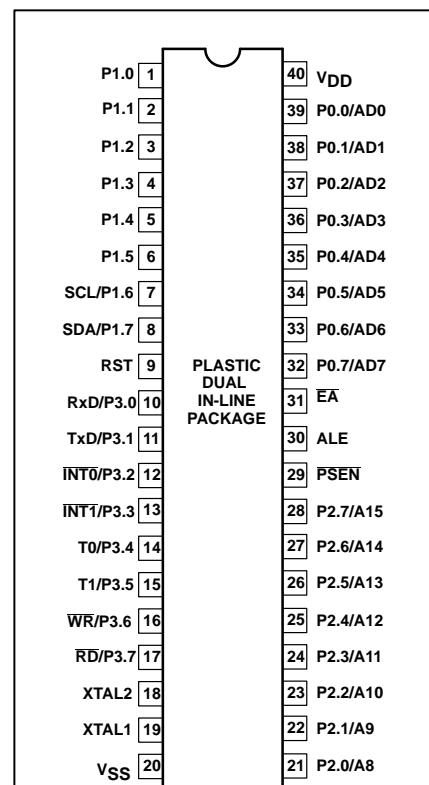
## LOGIC SYMBOL



## FEATURES

- 80C51 central processing unit
- 8k × 8 ROM expandable externally to 64k bytes
- 256 × 8 RAM, expandable externally to 64k bytes
- Two standard 16-bit timer/counters
- Four 8-bit I/O ports
- I<sup>2</sup>C-bus serial I/O port with byte oriented master and slave functions
- Full-duplex UART facilities
- Power control modes
  - Idle mode
  - Power-down mode
- ROM code protection
- Extended frequency range: 1.2 to 24 MHz
- Three operating ambient temperature ranges:
  - 0 to +70°C
  - 40 to +85°C
  - 40 to +125°C

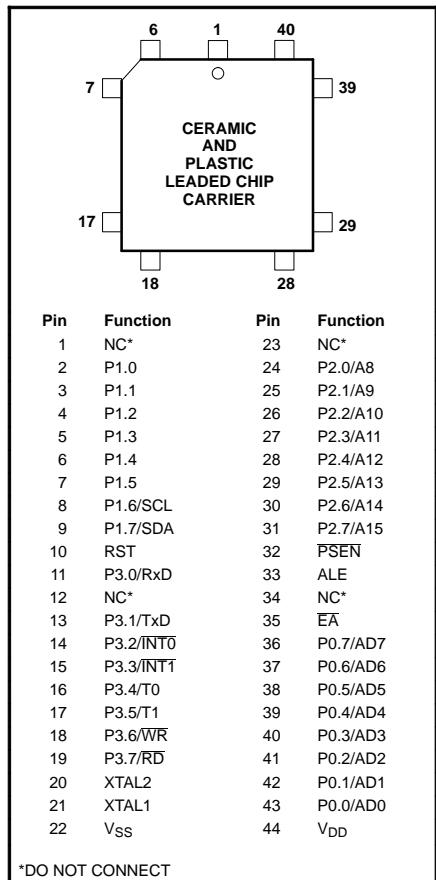
## PIN CONFIGURATIONS



## CMOS single-chip 8-bit microcontrollers

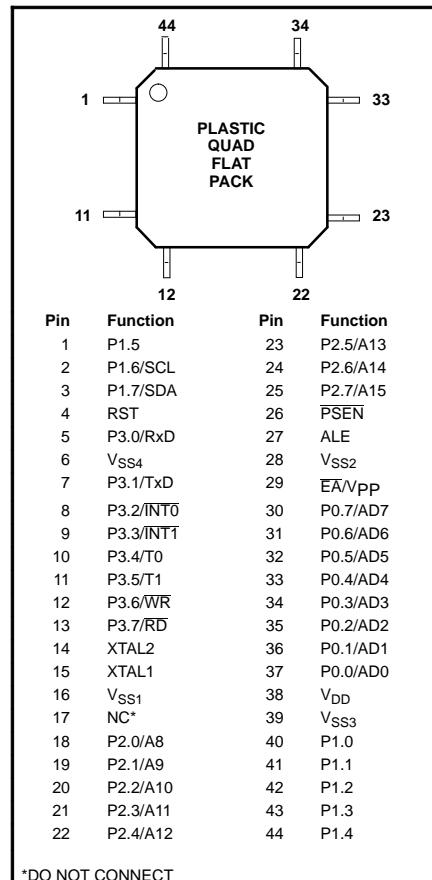
## 80C652/83C652

## CERAMIC AND PLASTIC LEADED CHIP CARRIER PIN FUNCTIONS



\*DO NOT CONNECT

## PLASTIC QUAD FLAT PACK PIN FUNCTIONS



\*DO NOT CONNECT

## NOTES TO QFP ONLY:

1. Due to EMC improvements, all V<sub>SS</sub> pins (6, 16, 28, 39) must be connected to V<sub>SS</sub> on the 80C652/83C652.

## CMOS single-chip 8-bit microcontrollers

## 80C652/83C652

## ORDER INFORMATION

PHILIPS PART ORDER NUMBER PART MARKING			PHILIPS NORTH AMERICA PART ORDER NUMBER		TEMPERATURE RANGE (°C) AND PACKAGE	FREQ MHz <sup>1,2</sup>
ROMless	ROM <sup>3</sup>	Drawing Number	ROMless	ROM		
P80C652FBP	P83C652FBP/xxx	SOT129-1	P80C652FBPN	P83C652FBPN	0 to +70, Plastic Dual In-line Package	16
P80C652FBA	P83C652FBA/xxx	SOT187-2	P80C652FBAA	P83C652FBAA	0 to +70, Plastic Leaded Chip Carrier	16
P80C652FBB	P83C652FBB/xxx	SOT307-2 <sup>4</sup>	P80C652FBBB	P83C652FBBB	0 to +70, Plastic Quad Flat Pack	16
P80C652FFP	P83C652FFP/xxx	SOT129-1	P80C652FFPN	P83C652FFPN	-40 to +85, Plastic Dual In-line Package	16
P80C652FFA	P83C652FFA/xxx	SOT187-2	P80C652FFAA	P83C652FFAA	-40 to +85, Plastic Leaded Chip Carrier	16
P80C652FFB	P83C652FFB/xxx	SOT307-2 <sup>4</sup>	P80C652FFBB	P83C652FFBB	-40 to +85, Plastic Quad Flat Pack	16
P80C652FHP	P83C652FHP/xxx	SOT129-1	P80C652FHPN	P83C652FHPN	-40 to +125, Plastic Dual In-line Package	16
P80C652FHA	P83C652FHA/xxx	SOT187-2	P80C652FHAA	P83C652FHAA	-40 to +125, Plastic Leaded Chip Carrier	16
P80C652FHB	P83C652FHB/xxx	SOT307-2 <sup>4</sup>	P80C652FHBB	P83C652FHBB	-40 to +125, Plastic Quad Flat Pack	16
P80C652IBP	P83C652IBP/xxx	SOT129-1	P80C652IBPN	P83C652IBPN	0 to +70, Plastic Dual In-line Package	24
P80C652IBA	P83C652IBA/xxx	SOT187-2	P80C652IBAA	P83C652IBAA	0 to +70, Plastic Leaded Chip Carrier	24
P80C652IBB	P83C652IBB/xxx	SOT307-2 <sup>4</sup>	P80C652IBBB	P83C652IBBB	0 to +70, Plastic Quad Flat Pack	24
P80C652IFP	P83C652IFP/xxx	SOT129-1	P80C652IFPN	P83C652IFPN	-40 to +85, Plastic Dual In-line Package	24
P80C652IFA	P83C652IFA/xxx	SOT187-2	P80C652IFAA	P83C652IFAA	-40 to +85, Plastic Leaded Chip Carrier	24
P80C652IFB	P83C652IFB/xxx	SOT307-2 <sup>4</sup>	P80C652IFBB	P83C652IFBB	-40 to +85, Plastic Quad Flat Pack	24

## NOTES:

1. 80C652 and 83C652 frequency range is 1.2MHz–16MHz or 1.2 to 24MHz.
2. For specification of the EPROM version, see the 87C652 data sheet.
3. xxx denotes the ROM code number.
4. SOT311 replaced by SOT307-2.

## CMOS single-chip 8-bit microcontrollers

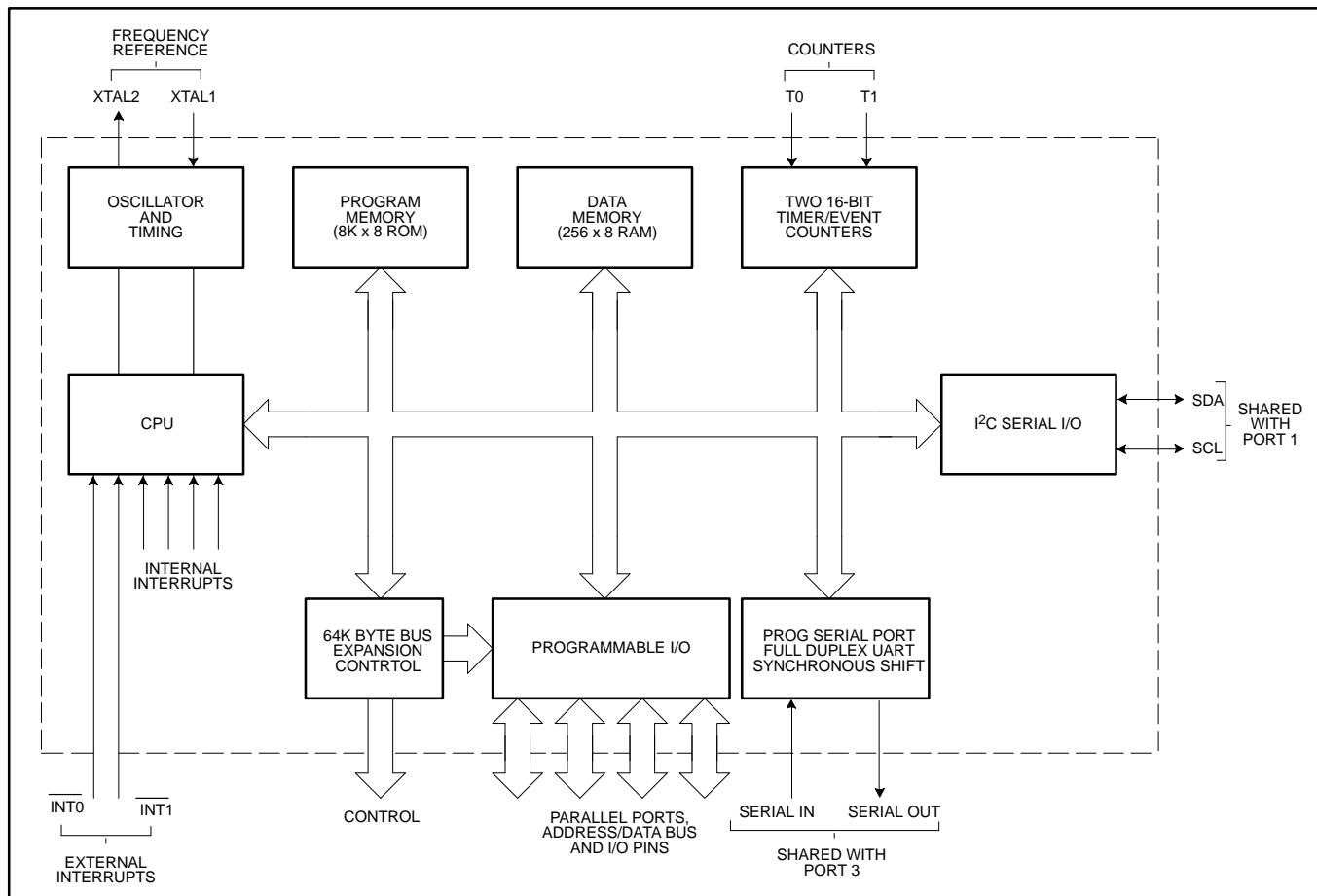
## 80C652/83C652

EPROM <sup>2</sup>	Drawing Number	TEMPERATURE RANGE (°C) AND PACKAGE	FREQ MHz <sup>1,2</sup>
S87C652-4N40	SOT129-1	0 to +70, Plastic Dual In-line Package	16
S87C652-4F40	0590B	0 to +70, Ceramic Dual In-line Package w/Window	16
S87C652-4A44	SOT187-2	0 to +70, Plastic Leaded Chip Carrier	16
S87C652-4K44	1472A	0 to +70, Ceramic Leaded Chip Carrier w/Window	16
S87C652-4B44	SOT307-2	0 to +70, Plastic Quad Flat Pack	16
S87C652-5N40	SOT129-1	−40 to +85, Plastic Dual In-line Package	16
S87C652-5F40	0590B	−40 to +85, Ceramic Dual In-line Package w/Window	16
S87C652-5A44	SOT187-2	−40 to +85, Plastic Leaded Chip Carrier	16
S87C652-5B44	SOT307-2	−40 to +85, Plastic Quad Flat Pack	16
S87C652-7N40	SOT129-1	0 to +70, Plastic Dual In-line Package	20
S87C652-7F40	0590B	0 to +70, Ceramic Dual In-line Package w/Window	20
S87C652-7A44	SOT187-2	0 to +70, Plastic Leaded Chip Carrier	20
S87C652-7K44	1472A	0 to +70, Ceramic Leaded Chip Carrier w/Window	20
S87C652-8N40	SOT129-1	−40 to +85, Plastic Dual In-line Package	20
S87C652-8F40	0590B	−40 to +85, Ceramic Dual In-line Package w/Window	20
S87C652-8A44	SOT187-2	−40 to +85, Plastic Leaded Chip Carrier	20

## CMOS single-chip 8-bit microcontrollers

80C652/83C652

## BLOCK DIAGRAM



## CMOS single-chip 8-bit microcontrollers

## 80C652/83C652

## PIN DESCRIPTIONS

MNEMONIC	PIN NUMBER			TYPE	NAME AND FUNCTION
	DIP	PLCC	QFP		
V <sub>SS</sub>	20	22	6, 16, 28, 39	I	<b>Ground:</b> 0V reference. With the QFP package all V <sub>SS</sub> pins (V <sub>SS1</sub> to V <sub>SS4</sub> ) must be connected.
V <sub>DD</sub>	40	44	38	I	<b>Power Supply:</b> This is the power supply voltage for normal, idle, and power-down operation.
P0.0–0.7	39–32	43–36	37–30	I/O	<b>Port 0:</b> Port 0 is an open-drain, bidirectional I/O port. Port 0 pins that have 1s written to them float and can be used as high-impedance inputs. Port 0 is also the multiplexed low-order address and data bus during accesses to external program and data memory. In this application, it uses strong internal pull-ups when emitting 1s.
P1.0–P1.7	1–8	2–9	40–44, 1–3	I/O	<b>Port 1:</b> Port 1 is an 8-bit bidirectional I/O port with internal pull-ups, except P1.6 and P1.7 which are open drain. Port 1 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 1 pins that are externally pulled low will source current because of the internal pull-ups. (See DC Electrical Characteristics: I <sub>IL</sub> ). Alternate functions include:  <b>SCL:</b> I <sup>2</sup> C-bus serial port clock line. <b>SDA:</b> I <sup>2</sup> C-bus serial port data line.
P2.0–P2.7	21–28	24–31	18–25	I/O	<b>Port 2:</b> Port 2 is an 8-bit bidirectional I/O port with internal pull-ups. Port 2 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 2 pins that are externally being pulled low will source current because of the internal pull-ups. (See DC Electrical Characteristics: I <sub>IL</sub> ). Port 2 emits the high-order address byte during fetches from external program memory and during accesses to external data memory that use 16-bit addresses (MOVX @DPTR). In this application, it uses strong internal pull-ups when emitting 1s. During accesses to external data memory that use 8-bit addresses (MOV @Ri), port 2 emits the contents of the P2 special function register.
P3.0–P3.7	10–17	11, 13–19	5, 7–13	I/O	<b>Port 3:</b> Port 3 is an 8-bit bidirectional I/O port with internal pull-ups. Port 3 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 3 pins that are externally being pulled low will source current because of the pull-ups. (See DC Electrical Characteristics: I <sub>IL</sub> ). Port 3 also serves the special features of the 80C51 family, as listed below:  10 11 5 I <b>RxD (P3.0):</b> Serial input port 11 13 7 O <b>TxD (P3.1):</b> Serial output port 12 14 8 I <b>INT0 (P3.2):</b> External interrupt 13 15 9 I <b>INT1 (P3.3):</b> External interrupt 14 16 10 I <b>T0 (P3.4):</b> Timer 0 external input 15 17 11 I <b>T1 (P3.5):</b> Timer 1 external input 16 18 12 O <b>WR (P3.6):</b> External data memory write strobe 17 19 13 O <b>RD (P3.7):</b> External data memory read strobe
RST	9	10	4	I	<b>Reset:</b> A high on this pin for two machine cycles while the oscillator is running, resets the device. An internal diffused resistor to V <sub>SS</sub> permits a power-on reset using only an external capacitor to V <sub>DD</sub> .
ALE	30	33	27	I/O	<b>Address Latch Enable:</b> Output pulse for latching the low byte of the address during an access to external memory. In normal operation, ALE is emitted at a constant rate of 1/6 the oscillator frequency. Note that one ALE pulse is skipped during each access to external data memory.
PSEN	29	32	26	O	<b>Program Store Enable:</b> Read strobe to external program memory via Port 0 and Port 2. It is activated twice each machine cycle during fetches from the external program memory. When executing out of external program memory two activations of PSEN are skipped during each access to external data memory. PSEN is not activated (remains HIGH) during no fetches from external program memory. PSEN can sink/source 8 LSTTL inputs and can drive CMOS inputs without external pull-ups.
EA	31	35	29	I	<b>External Access:</b> If during a RESET, EA is held at TTL level HIGH, the CPU executes out of the internal program memory ROM provided the Program Counter is less than 8192. If during a RESET, EA is held a TTL LOW level, the CPU executes out of external program memory. EA is not allowed to float.
XTAL1	19	21	15	I	<b>Crystal 1:</b> Input to the inverting oscillator amplifier and input to the internal clock generator circuits.
XTAL2	18	20	14	O	<b>Crystal 2:</b> Output from the inverting oscillator amplifier.

## NOTE:

To avoid "latch-up" effect at power-on, the voltage on any pin at any time must not be higher than V<sub>DD</sub> + 0.5V or V<sub>SS</sub> – 0.5V, respectively.

## CMOS single-chip 8-bit microcontrollers

## 80C652/83C652

Table 1. 8XC652/654 Special Function Registers

SYMBOL	DESCRIPTION	DIRECT ADDRESS	BIT ADDRESS, SYMBOL, OR ALTERNATIVE PORT FUNCTION									RESET VALUE
			MSB	LSB								
ACC*	Accumulator	E0H	E7	E6	E5	E4	E3	E2	E1	E0	00H	
B*	B register	F0H	F7	F6	F5	F4	F3	F2	F1	F0	00H	
DPTR:	Data pointer (2 bytes)											
DPH	Data pointer high	83H									00H	
DPL	Data pointer low	82H									00H	
IE*#	Interrupt enable	A8H	AF	AE	AD	AC	AB	AA	A9	A8	0x000000B	
			EA		ES1	ES0	ET1	EX1	ET0	EX0		
			BF	BE	BD	BC	BB	BA	B9	B8		
IP*#	Interrupt priority	B8H	–		PS1	PS0	PT1	PX1	PT0	PX0	xx000000B	
			87	86	85	84	83	82	81	80		
P0*	Port 0	80H	AD7	AD6	AD5	AD4	AD3	AD2	AD1	AD0	FFH	
			97	96	95	94	93	92	91	90		
P1*#	Port 1	90H	SDA	SCL							FFH	
			A7	A6	A5	A4	A3	A2	A1	A0		
P2*	Port 2	A0H	A15	A14	A13	A12	A11	A10	A9	A8	FFH	
			B7	B6	B5	B4	B3	B2	B1	B0		
P3*	Port 3	B0H	RD	WR	T1	T0	INT1	INT0	TXD	RXD	FFH	
PCON	Power control	87H	SMOD	–	–	–	GF1	GF0	PD	IDL	0xxx0000B	
			9F	9E	9D	9C	9B	9A	99	98		
S0CON*#	Serial 0 port control	98H	SM0	SM1	SM2	REN	TB8	RB8	TI	RI	00H	
S0BUF#	Serial 0 data buffer	99H									xxxxxxxB	
			D7	D6	D5	D4	D3	D2	D1	D0		
PSW*	Program status word	D0H	CY	AC	F0	RS1	RS0	OV	F1	P	00H	
S1DAT#	Serial 1 data	DAH									00H	
SP	Stack pointer	81H									07H	
S1ADR#	Serial 1 address	DBH	SLAVE ADDRESS								00H	
S1STA#	Serial 1 status	D9H	SC4	SC3	SC2	SC1	SC0	0	0	0	F8H	
			DF	DE	DD	DC	DB	DA	D9	D8		
S1CON*#	Serial 1 control	D8H	CR2	ENS1	STA	STO	SI	AA	CR1	CR0	0000000B	
			8F	8E	8D	8C	8B	8A	89	88		
TCON*	Timer control	88H	TF1	TR1	TF0	TR0	IE1	IT1	IE0	IT0	00H	
TH1	Timer high 1	8DH									00H	
TH0	Timer high 0	8CH									00H	
TL1	Timer low 1	8BH									00H	
TL0	Timer low 0	8AH									00H	
TMOD	Timer mode	89H	GATE	C/T	M1	M0	GATE	C/T	M1	M0	00H	

\* SFRs are bit addressable.

# SFRs are modified from or added to the 80C51 SFRs.

## CMOS single-chip 8-bit microcontrollers

## 80C652/83C652

**ROM CODE PROTECTION  
(83C652)**

The 8XC652 has an additional security feature. ROM code protection may be selected by setting a mask-programmable security bit (i.e., user dependent). This feature may be requested during ROM code submission. When selected, the ROM code is protected and cannot be read out at any time by any test mode or by any instruction in the external program memory space.

The MOVC instructions are the only instructions that have access to program code in the internal or external program memory. The EA input is latched during RESET and is "don't care" after RESET (also if the security bit is not set). This implementation prevents reading internal program code by switching from external program memory to internal program memory during a MOVC instruction or any other instruction that uses immediate data.

**OSCILLATOR  
CHARACTERISTICS**

XTAL1 and XTAL2 are the input and output, respectively, of an inverting amplifier. The pins can be configured for use as an on-chip oscillator, as shown in the Logic Symbol, page 2.

To drive the device from an external clock source, XTAL1 should be driven while XTAL2 is left unconnected. There are no requirements on the duty cycle of the external clock signal, because the input to the internal clock circuitry is through a divide-by-two flip-flop. However, minimum and maximum high and low times specified in the data sheet must be observed.

**Reset**

A reset is accomplished by holding the RST pin high for at least two machine cycles (24 oscillator periods), while the oscillator is running. To insure a good power-on reset, the RST pin must be high long enough to allow the oscillator time to start up (normally a few milliseconds) plus two machine cycles. At power-on, the voltage on  $V_{DD}$  and RST must come up at the same time for a proper start-up.

**Idle Mode**

In the idle mode, the CPU puts itself to sleep while all of the on-chip peripherals stay active. The instruction to invoke the idle mode is the last instruction executed in the normal operating mode before the idle mode is activated. The CPU contents, the on-chip RAM, and all of the special function registers remain intact during this mode. The idle mode can be terminated either by any

enabled interrupt (at which time the process is picked up at the interrupt service routine and continued), or by a hardware reset which starts the processor in the same manner as a power-on reset.

**Power-Down Mode**

In the power-down mode, the oscillator is stopped and the instruction to invoke power-down is the last instruction executed. Only the contents of the on-chip RAM are preserved. A hardware reset is the only way to terminate the power-down mode. The control bits for the reduced power modes are in the special function register PCON. Table 2 shows the state of the I/O ports during low current operating modes.

**I<sup>2</sup>C Serial Communication—SIO1**

The I<sup>2</sup>C serial port is identical to the I<sup>2</sup>C serial port on the 8XC552. The operation of this subsystem is described in detail in the 8XC552 section of this manual.

Note that in both the 8XC652/4 and the 8XC552 the I<sup>2</sup>C pins are alternate functions to port pins P1.6 and P1.7. Because of this, P1.6 and P1.7 on these parts do not have a pull-up structure as found on the 80C51. Therefore P1.6 and P1.7 have open drain outputs on the 8XC652/4.

**Table 2. External Pin Status During Idle and Power-Down Mode**

MODE	PROGRAM MEMORY	ALE	PSEN	PORT 0	PORT 1	PORT 2	PORT 3
Idle	Internal	1	1	Data	Data	Data	Data
Idle	External	1	1	Float	Data	Address	Data
Power-down	Internal	0	0	Data	Data	Data	Data
Power-down	External	0	0	Float	Data	Data	Data

**Serial Control Register (S1CON) – See Table 3**

S1CON (D8H) 

CR2	ENS1	STA	STO	SI	AA	CR1	CR0
-----	------	-----	-----	----	----	-----	-----

Bits CR0, CR1 and CR2 determine the serial clock frequency that is generated in the master mode of operation.

**Table 3. Serial Clock Rates**

CR2	CR1	CR0	BIT FREQUENCY (kHz) AT $f_{OSC}$				$f_{OSC}$ DIVIDED BY
			6MHz	12MHz	16MHz	24MHz	
0	0	0	23	47	62.5	94	256
0	0	1	27	54	71	107 <sup>1</sup>	224
0	1	0	31.25	62.5	83.3	125 <sup>1</sup>	192
0	1	1	37	75	100	150 <sup>1</sup>	160
1	0	0	6.25	12.5	17	25	960
1	0	1	50	100	133 <sup>1</sup>	200 <sup>1</sup>	120
1	1	0	100	200 <sup>1</sup>	267 <sup>1</sup>	400 <sup>1</sup>	60
1	1	1	0.24 < 62.5 0 to 255	0.49 < 62.5 0 to 254	0.65 < 55.6 0 to 253	0.98 < 50.0 0 to 251	96 × (256 – (reload value Timer 1)) reload value range Timer 1 (in mode 2)

**NOTES:**

- These frequencies exceed the upper limit of 100kHz of the I<sup>2</sup>C-bus specification and cannot be used in an I<sup>2</sup>C-bus application.

## CMOS single-chip 8-bit microcontrollers

80C652/83C652

ABSOLUTE MAXIMUM RATINGS<sup>1, 2, 3</sup>

PARAMETER	RATING	UNIT
Storage temperature range	–65 to +150	°C
Voltage on any other pin to V <sub>SS</sub>	–0.5 to + 6.5	V
Input, output current on any single pin	±5	mA
Power dissipation (based on package heat transfer limitations, not device power consumption)	1	W

## NOTES:

1. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any conditions other than those described in the AC and DC Electrical Characteristics section of this specification is not implied.
2. This product includes circuitry specifically designed for the protection of its internal devices from the damaging effects of excessive static charge. Nonetheless, it is suggested that conventional precautions be taken to avoid applying greater than the rated maxima.
3. Parameters are valid over operating temperature range unless otherwise specified. All voltages are with respect to V<sub>SS</sub> unless otherwise noted.

## DEVICE SPECIFICATIONS

TYPE	SUPPLY VOLTAGE (V)		FREQUENCY (MHz)		TEMPERATURE RANGE (°C)
	MIN.	MAX.	MIN.	MAX.	
P8XC652FBx	4.0	6.0	1.2	16	0 to +70
P8XC652FFx	4.0	6.0	1.2	16	–40 to +85
P8XC652FHx	4.5	5.5	1.2	16	–40 to +125
P8XC652IBx	4.5	5.5	1.2	24	0 to +70
P83X652IFx	4.5	5.5	1.2	24	–40 to +85

## CMOS single-chip 8-bit microcontrollers

## 80C652/83C652

## DC ELECTRICAL CHARACTERISTICS

 $V_{SS} = 0V$ 

SYMBOL	PARAMETER	PART TYPE	TEST CONDITIONS	LIMITS		UNIT
				MIN.	MAX.	
$V_{IL}$	Input low voltage, except EA, P1.6/SCL, P1.7/SDA		0 to +70°C -40 to +85°C -40 to +125°C	-0.5 -0.5 -0.5	0.2V <sub>DD</sub> -0.1 0.2V <sub>DD</sub> -0.15 0.2V <sub>DD</sub> -0.25	V V V
$V_{IL1}$	Input low voltage to EA		0 to +70°C -40 to +85°C -40 to +125°C	-0.5 -0.5 -0.5	0.2V <sub>DD</sub> -0.3 0.2V <sub>DD</sub> -0.35 0.2V <sub>DD</sub> -0.45	V V V
$V_{IL2}$	Input low voltage to P1.6/SCL, P1.7/SDA <sup>6</sup>			-0.5	0.3V <sub>DD</sub>	V
$V_{IH}$	Input high voltage, except XTAL1, RST, P1.6/SCL, P1.7/SDA		0 to +70°C -40 to +85°C -40 to +125°C		0.2V <sub>DD</sub> +0.9 0.2V <sub>DD</sub> +1.0 0.2V <sub>DD</sub> +1.0	V <sub>DD</sub> +0.5 V <sub>DD</sub> +0.5 V <sub>DD</sub> +0.5
$V_{IH1}$	Input high voltage, XTAL1, RST		0 to +70°C -40 to +85°C -40 to +125°C		0.7V <sub>DD</sub> 0.7V <sub>DD</sub> +0.1 0.7V <sub>DD</sub> +0.1	V <sub>DD</sub> +0.5 V <sub>DD</sub> +0.5 V <sub>DD</sub> +0.5
$V_{IH2}$	Input high voltage, P1.6/SCL, P1.7/SDA <sup>6</sup>				0.7V <sub>DD</sub>	6.0
$V_{OL}$	Output low voltage, ports 1, 2, 3, except P1.6/SCL, P1.7/SDA			$I_{OL} = 1.6\text{mA}^{8, 9}$		0.45
$V_{OL1}$	Output low voltage, port 0, ALE, PSEN			$I_{OL} = 3.2\text{mA}^{8, 9}$		0.45
$V_{OL2}$	Output low voltage, P1.6/SCL, P1.7/SDA			$I_{OL} = 3.0\text{mA}$		0.4
$V_{OH}$	Output high voltage, ports 1, 2, 3, ALE, PSEN <sup>10</sup>			$I_{OH} = -60\mu\text{A}$ $I_{OH} = -25\mu\text{A}$ $I_{OH} = -10\mu\text{A}$	2.4 0.75V <sub>DD</sub> 0.9V <sub>DD</sub>	V V V
$V_{OH1}$	Output high voltage; port 0 in external bus mode			$I_{OH} = -800\mu\text{A}$ $I_{OH} = -300\mu\text{A}$ $I_{OH} = -80\mu\text{A}$	2.4 0.75V <sub>DD</sub> 0.9V <sub>DD</sub>	V V V
$I_{IL}$	Logical 0 input current, ports 1, 2, 3, except P1.6/SCL, P1.7/SDA		0 to +70°C -40 to +85°C -40 to +125°C	$V_{IN} = 0.45\text{V}$	-50 -75 -75	$\mu\text{A}$ $\mu\text{A}$ $\mu\text{A}$
$I_{TL}$	Logical 1-to-0 transition current, ports 1, 2, 3, except P1.6/SCL, P1.7/SDA		0 to +70°C -40 to +85°C -40 to +125°C	See note 7	-650 -750 -750	$\mu\text{A}$ $\mu\text{A}$ $\mu\text{A}$
$I_{L1}$	Input leakage current, port 0, EA			$0.45\text{V} < V_I < V_{DD}$	$\pm 10$	$\mu\text{A}$
$I_{L2}$	Input leakage current, P1.6/SCL, P1.7/SDA			$0\text{V} < V_I < 6.0\text{V}$ $0\text{V} < V_{DD} < 6.0\text{V}$	$\pm 10$	$\mu\text{A}$ $\mu\text{A}$
$I_{DD}$	Power supply current: Active mode @ 16MHz <sup>2, 11</sup> Active mode @ 24MHz <sup>2, 11</sup> Idle mode @ 16MHz <sup>3, 11</sup> Idle mode @ 24MHz <sup>3, 11</sup> Power down mode <sup>4, 5</sup> Power down mode <sup>4, 5</sup>			See note 1 $V_{DD}=6.0\text{V}$ $V_{DD}=5.5\text{V}$	26.5 33.8 6 7 50 100	mA mA mA mA $\mu\text{A}$ $\mu\text{A}$
$R_{RST}$	Internal reset pull-down resistor				50	150
$C_{IO}$	Pin capacitance			Freq.=1MHz	10	pF

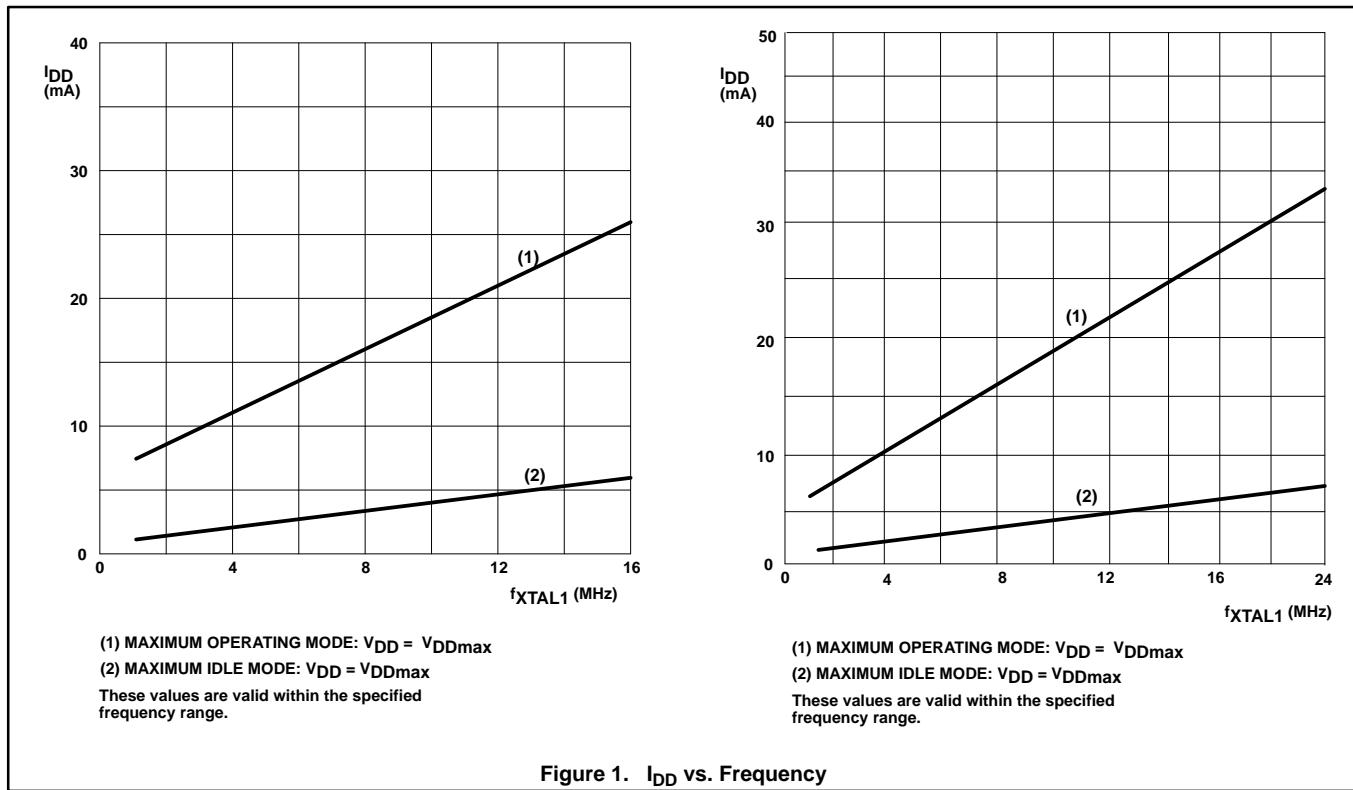
NOTES ON NEXT PAGE.

## CMOS single-chip 8-bit microcontrollers

## 80C652/83C652

## NOTES FOR DC ELECTRICAL CHARACTERISTICS:

1. See Figures 9 through 11 for  $I_{DD}$  test conditions.
2. The operating supply current is measured with all output pins disconnected; XTAL1 driven with  $t_r = t_f = 5\text{ns}$ ;  $V_{IL} = V_{SS} + 0.5\text{V}$ ;  $V_{IH} = V_{DD} - 0.5\text{V}$ ; XTAL2 not connected;  $\overline{EA} = RST = \text{Port 0} = \text{P1.6} = \text{P1.7} = V_{DD}$ . See Figure 9.
3. The idle mode supply current is measured with all output pins disconnected; XTAL1 driven with  $t_r = t_f = 5\text{ns}$ ;  $V_{IL} = V_{SS} + 0.5\text{V}$ ;  $V_{IH} = V_{DD} - 0.5\text{V}$ ; XTAL2 not connected; Port 0 = P1.6 = P1.7 =  $V_{DD}$ ;  $\overline{EA} = RST = V_{SS}$ . See Figure 10.
4. The power-down current is measured with all output pins disconnected; XTAL2 not connected; Port 0 = P1.6 = P1.7 =  $V_{DD}$ ;  $\overline{EA} = RST = V_{SS}$ . See Figure 11.
5.  $2\text{V} \leq V_{PD} \leq V_{DD\text{max}}$ .
6. The input threshold voltage of P1.6 and P1.7 (SIO1) meets the I<sup>2</sup>C specification, so an input voltage below  $0.3V_{DD}$  will be recognized as a logic 0 while an input voltage above  $0.7V_{DD}$  will be recognized as a logic 1.
7. Pins of ports 1, 2, and 3 source a transition current when they are being externally driven from 1 to 0. The transition current reaches its maximum value when  $V_{IN}$  is approximately  $2\text{V}$ .
8. Capacitive loading on ports 0 and 2 may cause spurious noise to be superimposed on the  $V_{OL}$ s of ALE and ports 1 and 3. The noise is due to external bus capacitance discharging into the port 0 and port 2 pins when these pins make 1-to-0 transitions during bus operations. In the worst cases (capacitive loading  $> 100\text{pF}$ ), the noise pulse on the ALE pin may exceed  $0.8\text{V}$ . In such cases, it may be desirable to qualify ALE with a Schmitt Trigger, or use an address latch with a Schmitt Trigger STROBE input.
9. Under steady state (non-transient) conditions,  $I_{OL}$  must be externally limited as follows: Maximum  $I_{OL} = 10\text{mA}$  per port pin; Maximum  $I_{OL} = 26\text{mA}$  total for Port 0; Maximum  $I_{OL} = 15\text{mA}$  total for Ports 1, 2, and 3; Maximum  $I_{OL} = 71\text{mA}$  total for all output pins. If  $I_{OL}$  exceeds the test conditions,  $V_{OL}$  may exceed the related specification. Pins are not guaranteed to sink current greater than the listed test conditions.
10. Capacitive loading on ports 0 and 2 may cause the  $V_{OH}$  on ALE and  $\overline{PSEN}$  to momentarily fall below the  $0.9V_{DD}$  specification when the address bits are stabilizing.
11.  $I_{DD\text{MAX}}$  for other frequencies can be derived from Figure 1, where FREQ is the external oscillator frequency in MHz.  $I_{DD\text{MAX}}$  is given in mA.

Figure 1.  $I_{DD}$  vs. Frequency

## CMOS single-chip 8-bit microcontrollers

## 80C652/83C652

AC ELECTRICAL CHARACTERISTICS<sup>1, 2</sup> (16 MHz type)

SYMBOL	FIGURE	PARAMETER	16MHz CLOCK		VARIABLE CLOCK		UNIT
			MIN	MAX	MIN	MAX	
$t_{CLCL}$	2	Oscillator frequency			1.2	16	MHz
$t_{LHLL}$	2	ALE pulse width	85		$2t_{CLCL}-40$		ns
$t_{AVLL}$	2	Address valid to ALE low	8		$t_{CLCL}-55$		ns
$t_{LLAX}$	2	Address hold after ALE low	28		$t_{CLCL}-35$		ns
$t_{LLIV}$	2	ALE low to valid instruction in		150		$4t_{CLCL}-100$	ns
$t_{LLPL}$	2	ALE low to $\overline{PSEN}$ low	23		$t_{CLCL}-40$		ns
$t_{PLPH}$	2	$\overline{PSEN}$ pulse width	143		$3t_{CLCL}-45$		ns
$t_{PLIV}$	2	$\overline{PSEN}$ low to valid instruction in		83		$3t_{CLCL}-105$	ns
$t_{PXIX}$	2	Input instruction hold after $\overline{PSEN}$	0		0		ns
$t_{PXIZ}$	2	Input instruction float after $\overline{PSEN}$		38		$t_{CLCL}-25$	ns
$t_{AVIV}$	2	Address to valid instruction in		208		$5t_{CLCL}-105$	ns
$t_{PLAZ}$	2	$\overline{PSEN}$ low to address float		10		10	ns
<b>Data Memory</b>							
$t_{RLRH}$	3, 4	$\overline{RD}$ pulse width	275		$6t_{CLCL}-100$		ns
$t_{WLWH}$	3, 4	$\overline{WR}$ pulse width	275		$6t_{CLCL}-100$		ns
$t_{RLDV}$	3, 4	$\overline{RD}$ low to valid data in		148		$5t_{CLCL}-165$	ns
$t_{RHDX}$	3, 4	Data hold after $\overline{RD}$	0		0		ns
$t_{RHDZ}$	3, 4	Data float after $\overline{RD}$		55		$2t_{CLCL}-70$	ns
$t_{LLDV}$	3, 4	ALE low to valid data in		350		$8t_{CLCL}-150$	ns
$t_{AVDV}$	3, 4	Address to valid data in		398		$9t_{CLCL}-165$	ns
$t_{LLWL}$	3, 4	ALE low to $\overline{RD}$ or $\overline{WR}$ low	138	238	$3t_{CLCL}-50$	$3t_{CLCL}+50$	ns
$t_{AVWL}$	3, 4	Address valid to $\overline{WR}$ low or $\overline{RD}$ low	120		$4t_{CLCL}-130$		ns
$t_{QVWX}$	3, 4	Data valid to $\overline{WR}$ transition	3		$t_{CLCL}-60$		ns
$t_{DW}$	3, 4	Data setup time before $\overline{WR}$	288		$7t_{CLCL}-150$		ns
$t_{WHQX}$	3, 4	Data hold after $\overline{WR}$	13		$t_{CLCL}-50$		ns
$t_{RLAZ}$	3, 4	$\overline{RD}$ low to address float		0		0	ns
$t_{WHLH}$	3, 4	$\overline{RD}$ or $\overline{WR}$ high to ALE high	23	103	$t_{CLCL}-40$	$t_{CLCL}+40$	ns
<b>Shift Register</b>							
$t_{XLXL}$	5	Serial port clock cycle time <sup>3</sup>	0.75		$12t_{CLCL}$		$\mu s$
$t_{QVXH}$	5	Output data setup to clock rising edge <sup>3</sup>	492		$10t_{CLCL}-133$		ns
$t_{XHQX}$	5	Output data hold after clock rising edge <sup>3</sup>	80		$2t_{CLCL}-117$		ns
$t_{XHDX}$	5	Input data hold after clock rising edge <sup>3</sup>	0		0		ns
$t_{XHDV}$	5	Clock rising edge to input data valid <sup>3</sup>		492		$10t_{CLCL}-133$	ns
<b>External Clock</b>							
$t_{CHCX}$	6	High time <sup>3</sup>	20		20	$t_{CLCL} - t_{CLCX}$	ns
$t_{CLCX}$	6	Low time <sup>3</sup>	20		20	$t_{CLCL} - t_{CHCX}$	ns
$t_{CLCH}$	6	Rise time <sup>3</sup>		20		20	ns
$t_{CHCL}$	6	Fall time <sup>3</sup>		20		20	ns

**NOTES:**

1. Parameters are valid over operating temperature range unless otherwise specified.
2. Load capacitance for port 0, ALE, and  $\overline{PSEN}$  = 100pF, load capacitance for all other outputs = 80pF.
3. These values are characterized but not 100% production tested.

## CMOS single-chip 8-bit microcontrollers

## 80C652/83C652

AC ELECTRICAL CHARACTERISTICS<sup>1, 2</sup> (24 MHz type)

SYMBOL	FIGURE	PARAMETER	24MHz CLOCK		VARIABLE CLOCK		UNIT
			MIN	MAX	MIN	MAX	
$t_{CLCL}$	2	Oscillator frequency			1.2	24	MHz
$t_{LHLL}$	2	ALE pulse width	43		$2t_{CLCL}-40$		ns
$t_{AVLL}$	2	Address valid to ALE low	17		$t_{CLCL}-25$		ns
$t_{LLAX}$	2	Address hold after ALE low	17		$t_{CLCL}-25$		ns
$t_{LLIV}$	2	ALE low to valid instruction in		102		$4t_{CLCL}-65$	ns
$t_{LLPL}$	2	ALE low to $\overline{PSEN}$ low	17		$t_{CLCL}-25$		ns
$t_{PLPH}$	2	$\overline{PSEN}$ pulse width	80		$3t_{CLCL}-45$		ns
$t_{PLIV}$	2	$\overline{PSEN}$ low to valid instruction in		65		$3t_{CLCL}-60$	ns
$t_{PXIX}$	2	Input instruction hold after $\overline{PSEN}$	0		0		ns
$t_{PXIZ}$	2	Input instruction float after $\overline{PSEN}$		17		$t_{CLCL}-25$	ns
$t_{AVIV}$	2	Address to valid instruction in		128		$5t_{CLCL}-80$	ns
$t_{PLAZ}$	2	$\overline{PSEN}$ low to address float		10		10	ns
<b>Data Memory</b>							
$t_{RLRH}$	3, 4	$\overline{RD}$ pulse width	150		$6t_{CLCL}-100$		ns
$t_{WLWH}$	3, 4	$\overline{WR}$ pulse width	150		$6t_{CLCL}-100$		ns
$t_{RLDV}$	3, 4	$\overline{RD}$ low to valid data in		118		$5t_{CLCL}-90$	ns
$t_{RHDX}$	3, 4	Data hold after $\overline{RD}$	0		0		ns
$t_{RHDZ}$	3, 4	Data float after $\overline{RD}$		55		$2t_{CLCL}-28$	ns
$t_{LLDV}$	3, 4	ALE low to valid data in		180		$8t_{CLCL}-150$	ns
$t_{AVDV}$	3, 4	Address to valid data in		210		$9t_{CLCL}-165$	ns
$t_{LLWL}$	3, 4	ALE low to $\overline{RD}$ or $\overline{WR}$ low	75	175	$3t_{CLCL}-50$	$3t_{CLCL}+50$	ns
$t_{AVWL}$	3, 4	Address valid to $\overline{WR}$ low or $\overline{RD}$ low	92		$4t_{CLCL}-75$		ns
$t_{QVWX}$	3, 4	Data valid to $\overline{WR}$ transition	12		$t_{CLCL}-30$		ns
$t_{DW}$	3, 4	Data setup time before $\overline{WR}$	162		$7t_{CLCL}-130$		ns
$t_{WHQX}$	3, 4	Data hold after $\overline{WR}$	17		$t_{CLCL}-25$		ns
$t_{RLAZ}$	3, 4	$\overline{RD}$ low to address float		0		0	ns
$t_{WHLH}$	3, 4	$\overline{RD}$ or $\overline{WR}$ high to ALE high	17	67	$t_{CLCL}-25$	$t_{CLCL}+25$	ns
<b>Shift Register</b>							
$t_{XLXL}$	5	Serial port clock cycle time <sup>3</sup>	0.5		$12t_{CLCL}$		$\mu s$
$t_{QVXH}$	5	Output data setup to clock rising edge <sup>3</sup>	283		$10t_{CLCL}-133$		ns
$t_{XHQX}$	5	Output data hold after clock rising edge <sup>3</sup>	23		$2t_{CLCL}-60$		ns
$t_{XHDX}$	5	Input data hold after clock rising edge <sup>3</sup>	0		0		ns
$t_{XHDV}$	5	Clock rising edge to input data valid <sup>3</sup>		283		$10t_{CLCL}-133$	ns
<b>External Clock</b>							
$t_{CHCX}$	6	High time <sup>3</sup>	17		17	$t_{CLCL} - t_{CLCX}$	ns
$t_{CLCX}$	6	Low time <sup>3</sup>	17		17	$t_{CLCL} - t_{CHCX}$	ns
$t_{CLCH}$	6	Rise time <sup>3</sup>		5		5	ns
$t_{CHCL}$	6	Fall time <sup>3</sup>		5		5	ns

**NOTES:**

1. Parameters are valid over operating temperature range unless otherwise specified.
2. Load capacitance for port 0, ALE, and  $\overline{PSEN}$  = 100pF, load capacitance for all other outputs = 80pF.
3. These values are characterized but not 100% production tested.

## CMOS single-chip 8-bit microcontrollers

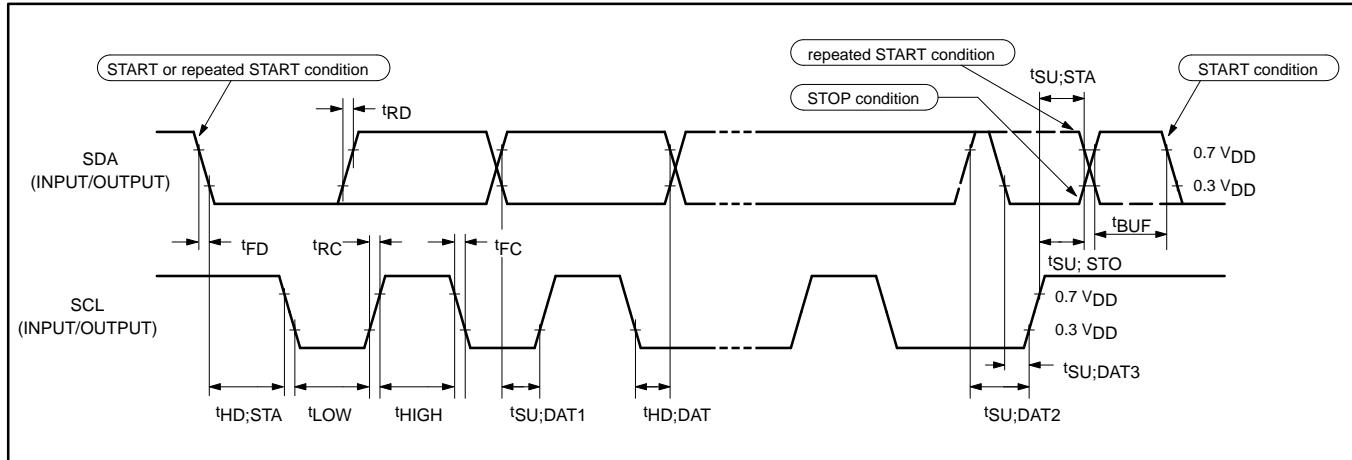
## 80C652/83C652

AC ELECTRICAL CHARACTERISTICS – I<sup>2</sup>C INTERFACE

SYMBOL	PARAMETER	INPUT	OUTPUT
<b>SCL TIMING CHARACTERISTICS</b>			
$t_{HD;STA}$	START condition hold time	$\geq 14 t_{CLCL}$	$> 4.0\mu s^1$
$t_{LOW}$	SCL LOW time	$\geq 16 t_{CLCL}$	$> 4.7\mu s^1$
$t_{HIGH}$	SCL HIGH time	$\geq 14 t_{CLCL}$	$> 4.0\mu s^1$
$t_{RC}$	SCL rise time	$\leq 1\mu s$	$-^2$
$t_{FC}$	SCL fall time	$\leq 0.3\mu s$	$< 0.3\mu s^3$
<b>SDA TIMING CHARACTERISTICS</b>			
$t_{SU;DAT1}$	Data set-up time	$\geq 250\text{ns}$	$> 20 t_{CLCL} - t_{RD}$
$t_{SU;DAT2}$	SDA set-up time (before rep. START cond.)	$\geq 250\text{ns}$	$> 1\mu s^1$
$t_{SU;DAT3}$	SDA set-up time (before STOP cond.)	$\geq 250\text{ns}$	$> 8 t_{CLCL}$
$t_{HD;DAT}$	Data hold time	$\geq 0\text{ns}$	$> 8 t_{CLCL} - t_{FC}$
$t_{SU;STA}$	Repeated START set-up time	$\geq 14 t_{CLCL}$	$> 4.7\mu s^1$
$t_{SU;STO}$	STOP condition set-up time	$\geq 14 t_{CLCL}$	$> 4.0\mu s^1$
$t_{BUF}$	Bus free time	$\geq 14 t_{CLCL}$	$> 4.7\mu s^1$
$t_{RD}$	SDA rise time	$\leq 1\mu s$	$-^2$
$t_{FD}$	SDA fall time	$\leq 0.3\mu s$	$< 0.3\mu s^3$

## NOTES:

1. At 100 kbit/s. At other bit rates this value is inversely proportional to the bit-rate of 100 kbit/s.
2. Determined by the external bus-line capacitance and the external bus-line pull-resistor, this must be  $< 1\mu s$ .
3. Spikes on the SDA and SCL lines with a duration of less than  $3 t_{CLCL}$  will be filtered out. Maximum capacitance on bus-lines SDA and SCL = 400pF.
4.  $t_{CLCL} = 1/f_{osc}$  = one oscillator clock period at pin XTAL1. For 63ns (42ns)  $< t_{CLCL} < 285\text{ns}$  (16MHz (24MHz)  $> f_{osc} > 3.5\text{MHz}$ ) the SIO1 interface meets the I<sup>2</sup>C-bus specification for bit-rates up to 100 kbit/s.

TIMING SIO1 (I<sup>2</sup>C) INTERFACE

## CMOS single-chip 8-bit microcontrollers

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## EXPLANATION OF THE AC SYMBOLS

Each timing symbol has five characters. The first character is always 't' (= time). The other characters, depending on their positions, indicate the name of a signal or the logical status of that signal. The designations are:

A – Address  
C – Clock  
D – Input data  
H – Logic level high  
I – Instruction (program memory contents)  
L – Logic level low, or ALE  
P –  $\overline{PSEN}$

Q – Output data  
R –  $\overline{RD}$  signal  
t – Time  
V – Valid  
W –  $\overline{WR}$  signal  
X – No longer a valid logic level  
Z – Float

**Examples:**  $t_{AVLL}$  = Time for address valid

to ALE low.

$t_{LLPL}$  = Time for ALE low  
to  $\overline{PSEN}$  low.

$t_{PLPH}$

$t_{PLIV}$

$t_{PLAZ}$

$t_{PXIZ}$

$t_{PXIX}$

$t_{AVIV}$

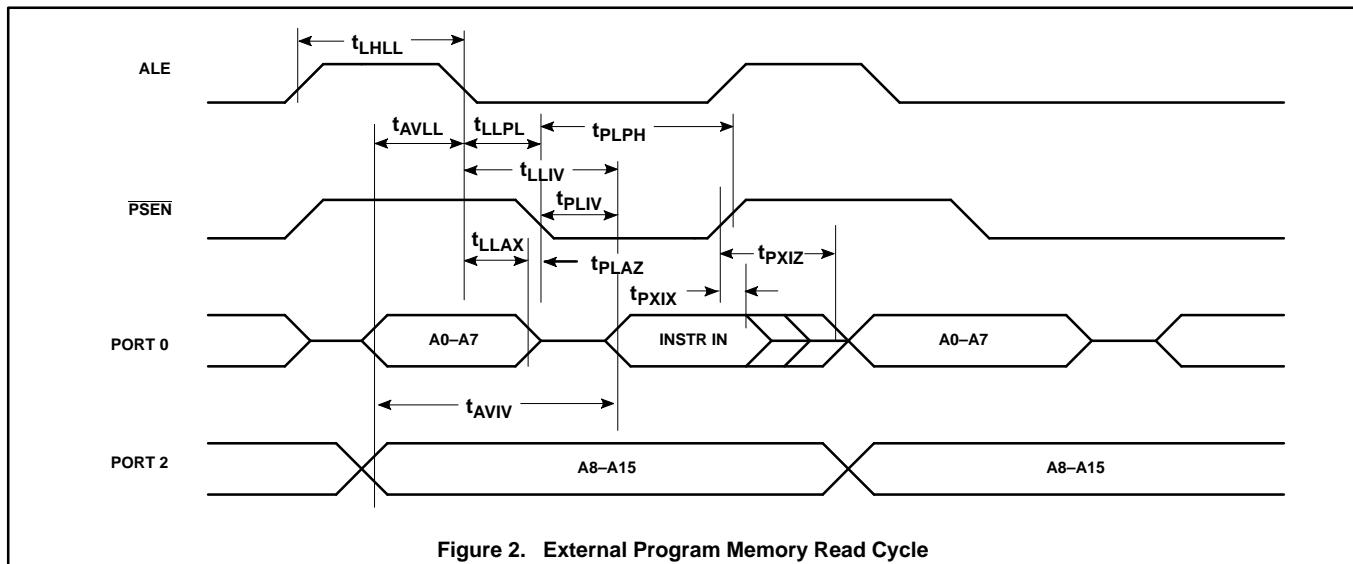


Figure 2. External Program Memory Read Cycle

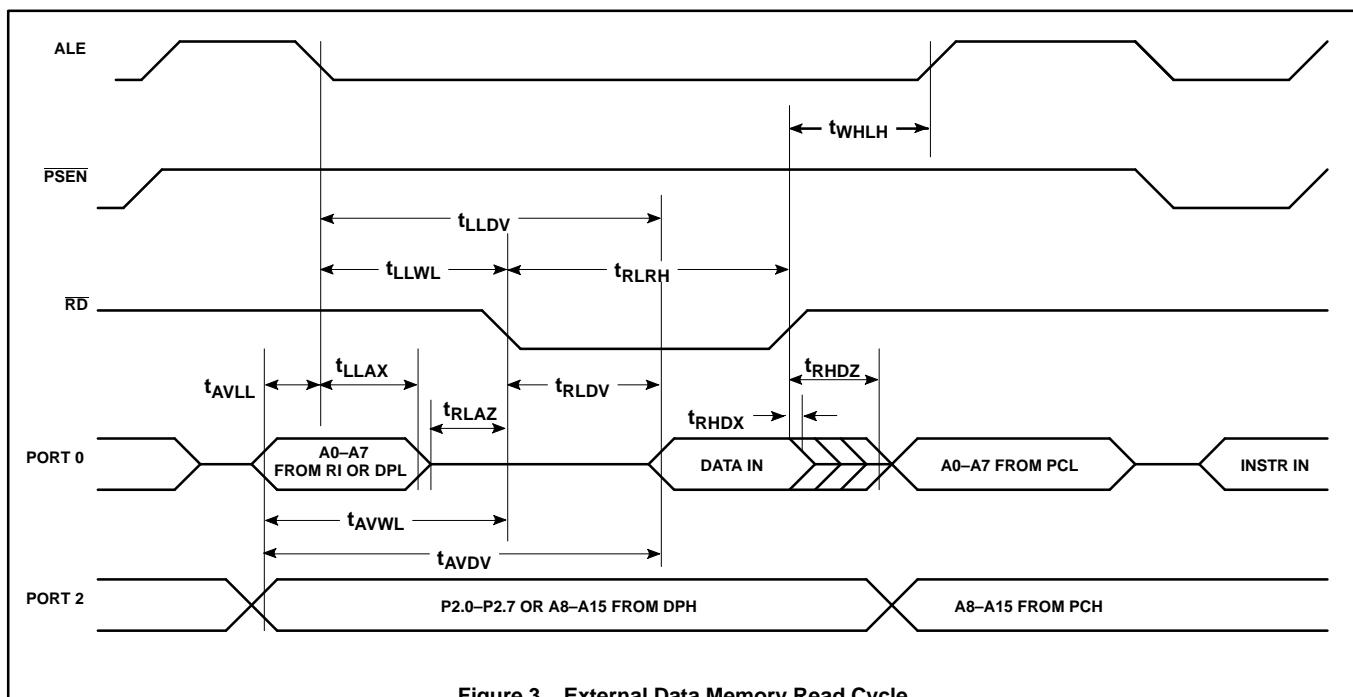


Figure 3. External Data Memory Read Cycle

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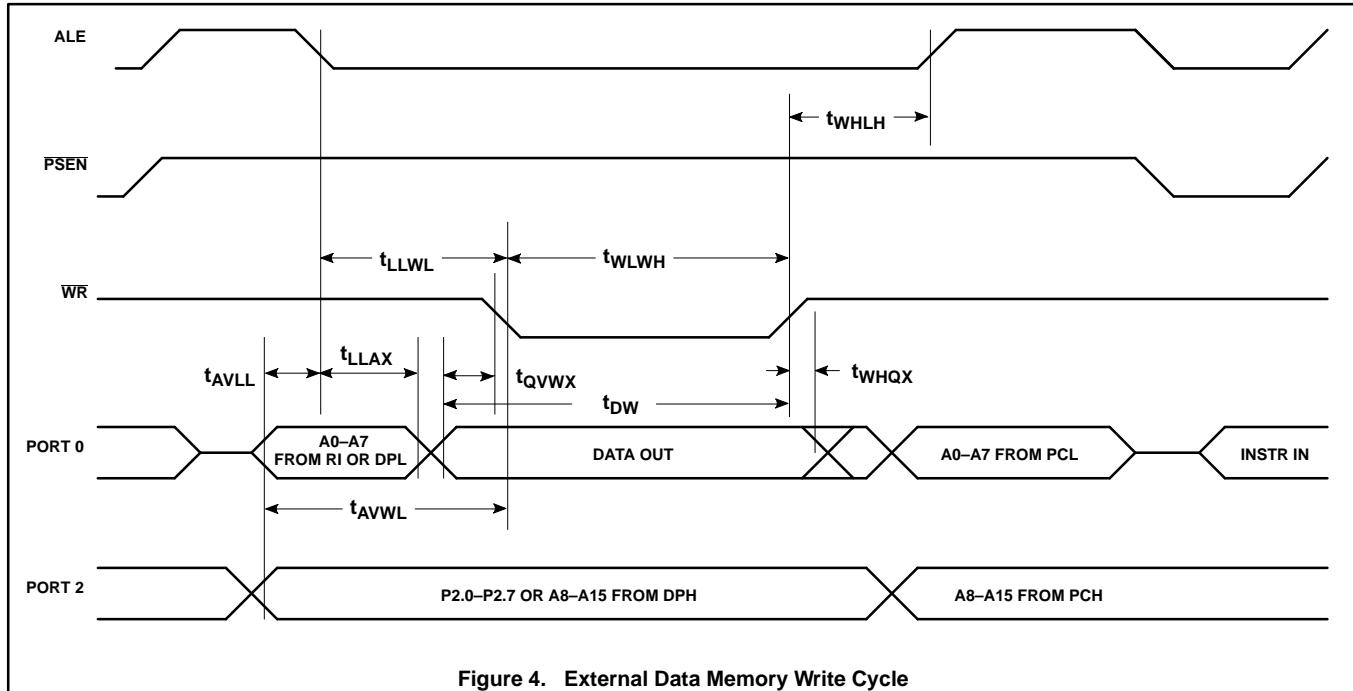


Figure 4. External Data Memory Write Cycle

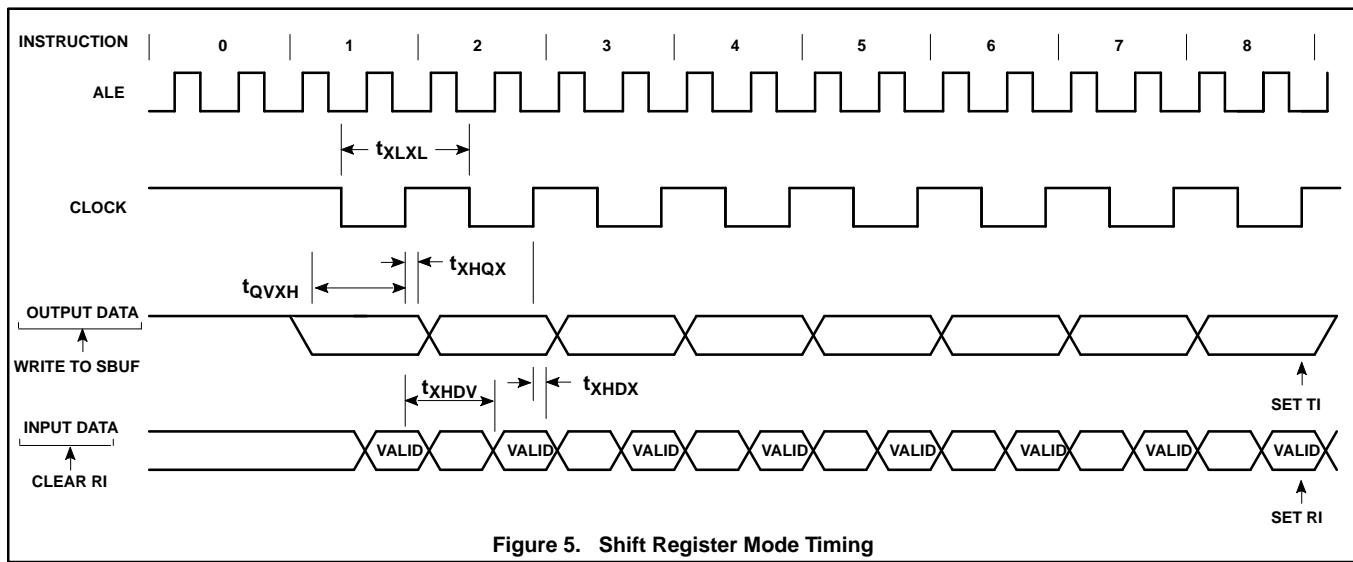


Figure 5. Shift Register Mode Timing

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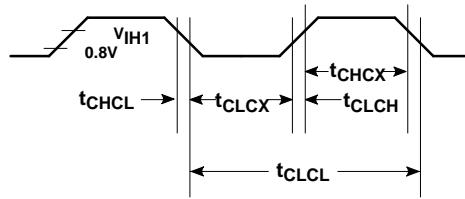


Figure 6. External Clock Drive at XTAL1



## NOTE:

AC INPUTS DURING TESTING ARE DRIVEN AT  $V_{DD}-0.5$  FOR A LOGIC '1' AND 0.45V FOR A LOGIC '0'. TIMING MEASUREMENTS ARE MADE AT  $V_{IH}$  MIN FOR A LOGIC '1' AND  $V_{IL}$  MAX FOR A LOGIC '0'.

Figure 7. AC Testing Input/Output

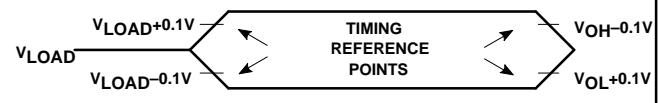


Figure 8. Float Waveform

NOTE:  
FOR TIMING PURPOSES, A PORT IS NO LONGER FLOATING WHEN A 100mV CHANGE FROM LOAD VOLTAGE OCCURS, AND BEGINS TO FLOAT WHEN A 100mV CHANGE FROM THE LOADED  $V_{OH}/V_{OL}$  LEVEL OCCURS.  $|I_{OH}/I_{OL}| \geq \pm 20\text{mA}$ .

## CMOS single-chip 8-bit microcontrollers

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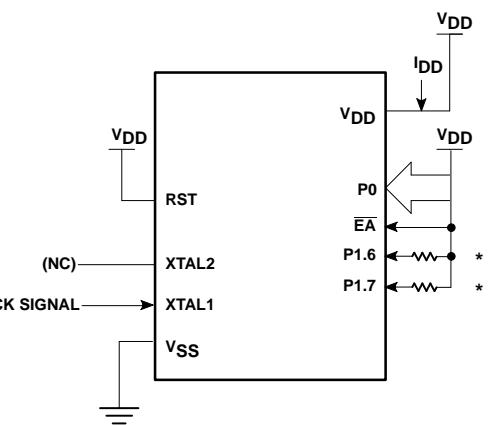


Figure 9.  $I_{DD}$  Test Condition, Active Mode  
All other pins are disconnected

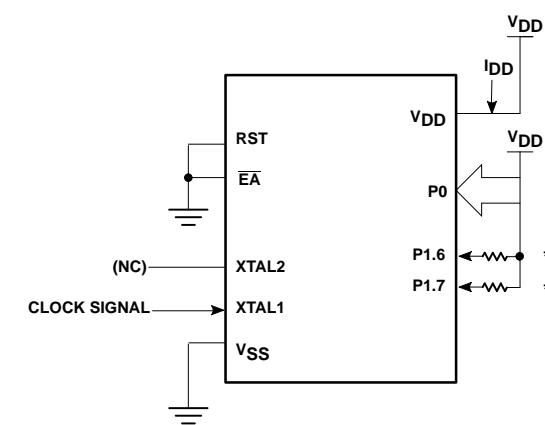


Figure 10.  $I_{DD}$  Test Condition, Idle Mode  
All other pins are disconnected

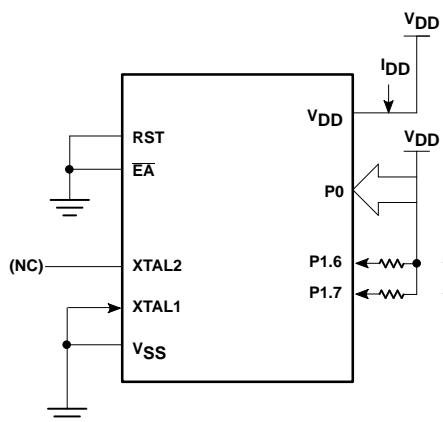


Figure 11.  $I_{DD}$  Test Condition, Power Down Mode  
All other pins are disconnected.  $V_{DD} = 2V$  to  $5.5V$

## NOTE:

\* Ports 1.6 and 1.7 should be connected to  $V_{CC}$  through resistors of sufficiently high value such that the sink current into these pins does not exceed the  $I_{OL1}$  specification.



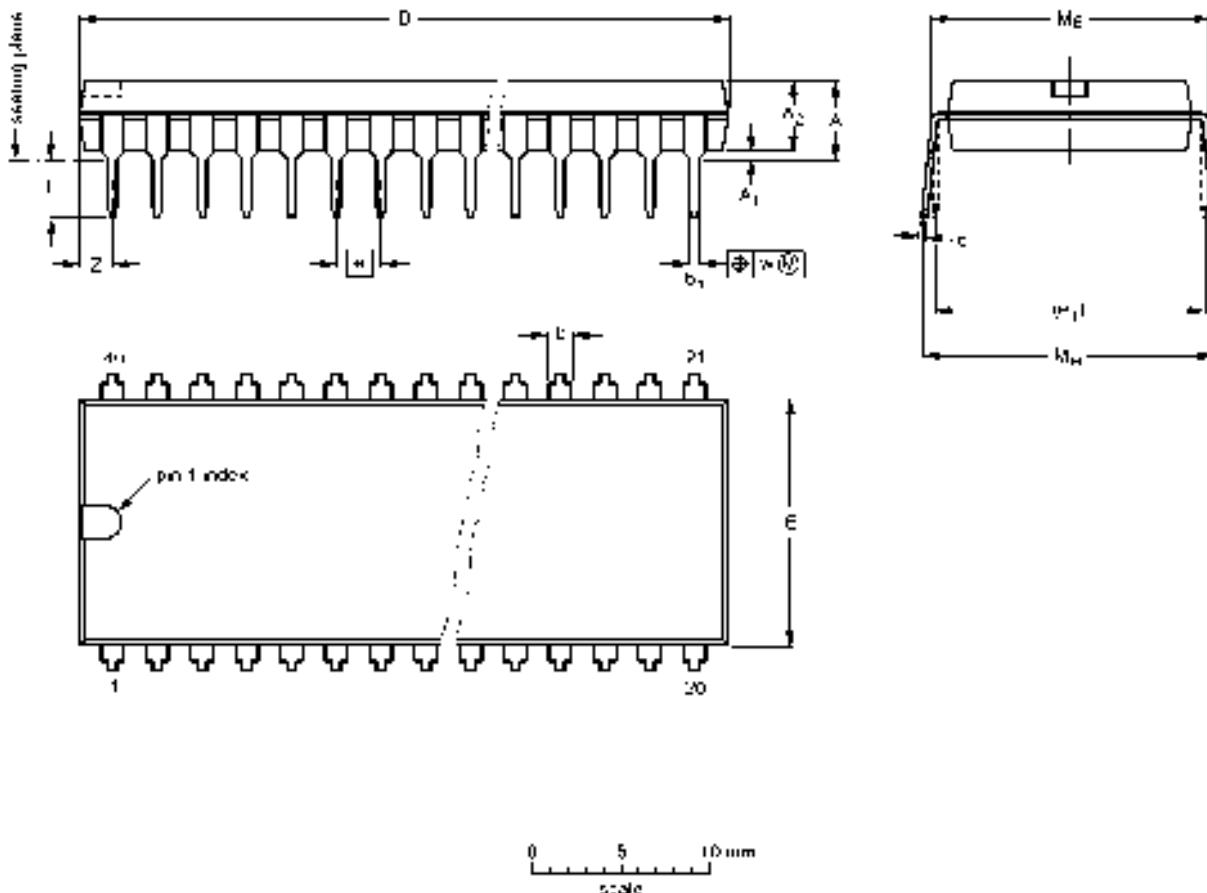
Purchase of Philips I<sup>2</sup>C components conveys a license under the Philips' I<sup>2</sup>C patent to use the components in the I<sup>2</sup>C system provided the system conforms to the I<sup>2</sup>C specifications defined by Philips. This specification can be ordered using the code 9398 393 40011.

## CMOS single-chip 8-bit microcontrollers

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DIP40: plastic dual in-line package; 40 leads (600 mil)

SOT129-1



DIMENSIONS (Inch dimensions are derived from the original mm dimensions)

UNIT	$A$ max.	$A_1$ min.	$A_2$ max.	$b$	$b_1$	$c$	$D^{(1)}$	$E^{(1)}$	$L$	$L_1$	$M_E$	$M_H$	$w$	$Z^{(1)}$ max.
mm	4.7	0.51	4.0	11.70 11.14	0.50 0.38	0.38 0.20	0.30 31.50	14.1 13.7	2.54	15.74	15.00 15.63	15.42 15.90	0.254	2.25
inches	0.185	0.020	0.16	0.467 0.446	0.021 0.015	0.014 0.008	0.012 0.009	0.554	0.10	0.60	0.592 0.60	0.595 0.60	0.01 0.01	0.008

## Note

1 Plastic or metal protrusions of 0.25 mm maximum per side are not included.

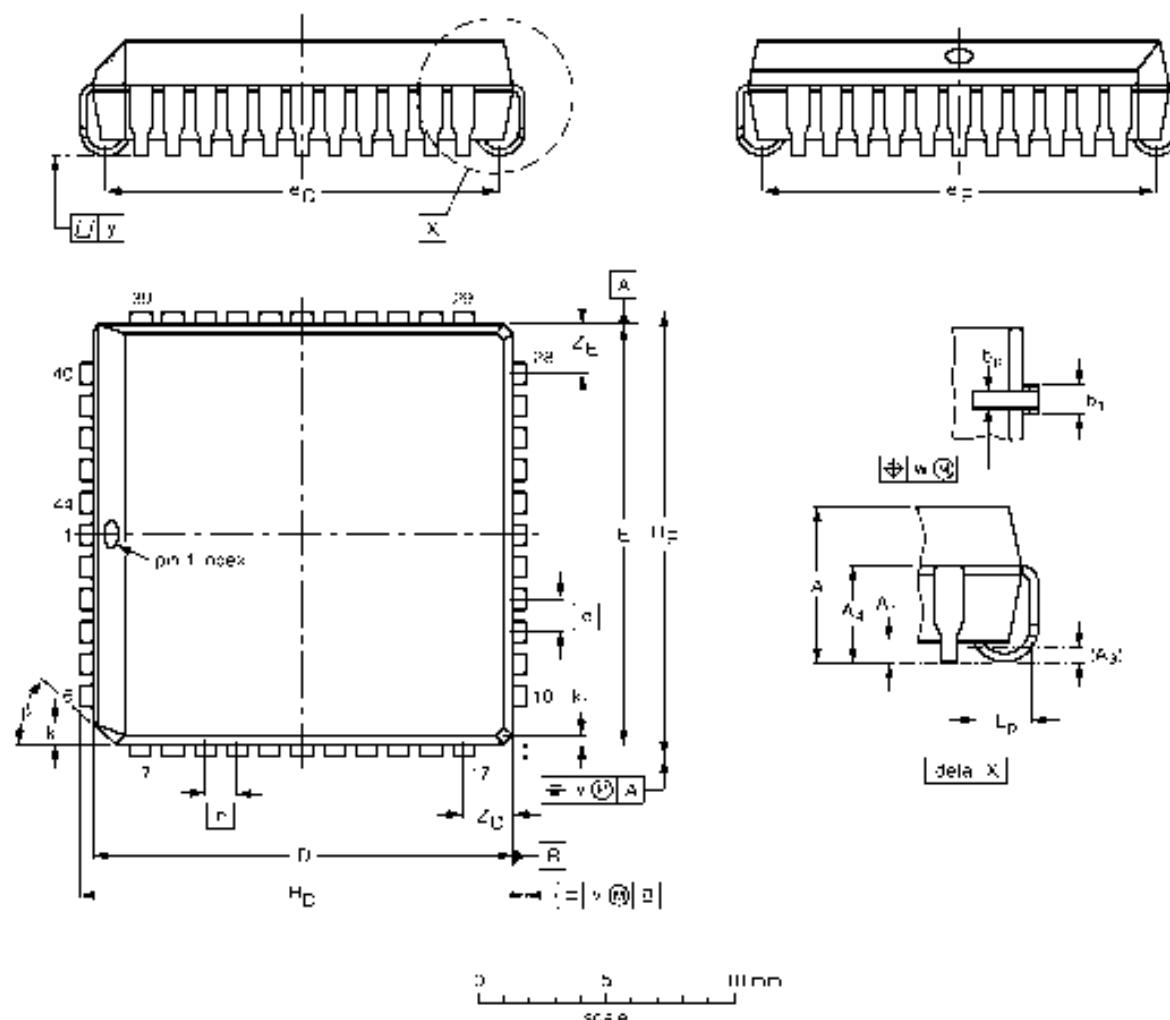
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT129-1	Q51GQR	MO-015AJ				92-11-14 95-01-14

## CMOS single-chip 8-bit microcontrollers

80C652/83C652

## PLCC44: plastic leaded chip carrier; 44 leads

SOT187-2



DIMENSIONS (millimetre dimensions are derived from the original inch dimensions)

UNIT	A	A <sub>1</sub> min.	A <sub>2</sub>	A <sub>3</sub>	A <sub>4</sub> max.	b <sub>P</sub>	b <sub>1</sub>	D <sup>(1)</sup>	E <sup>(1)</sup>	e	e <sub>D</sub>	e <sub>E</sub>	H <sub>D</sub>	H <sub>E</sub>	k	k <sub>1</sub> max.	L <sub>P</sub>	v	w	y	Z <sub>D</sub> <sup>(1)</sup> max.	Z <sub>E</sub> <sup>(1)</sup> max.	β
mm	4.67	0.51	0.95	3.05	0.50	0.61	16.66	16.66	16.66	1.27	16.00	16.00	17.65	17.65	1.22	2.01	1.44	0.16	0.18	0.10	2.16	2.16	±5%
	4.49	0.51	0.95	3.05	0.50	0.66	16.51	16.51	16.51	1.27	14.39	14.39	17.40	17.40	1.27	2.01	1.42	0.16	0.18	0.10	2.16	2.16	
inches	0.182	0.020	0.037	0.125	0.020	0.032	0.650	0.650	0.650	0.051	0.630	0.630	0.660	0.660	0.051	0.046	0.037	0.007	0.007	0.007	0.024	0.024	0.045
	0.165	0.020	0.037	0.125	0.020	0.026	0.650	0.650	0.650	0.051	0.630	0.630	0.660	0.660	0.051	0.042	0.042	0.007	0.007	0.007	0.024	0.024	0.045

## Note

1 Plastic or metal protrusions of 0.01 inches maximum per side are not included

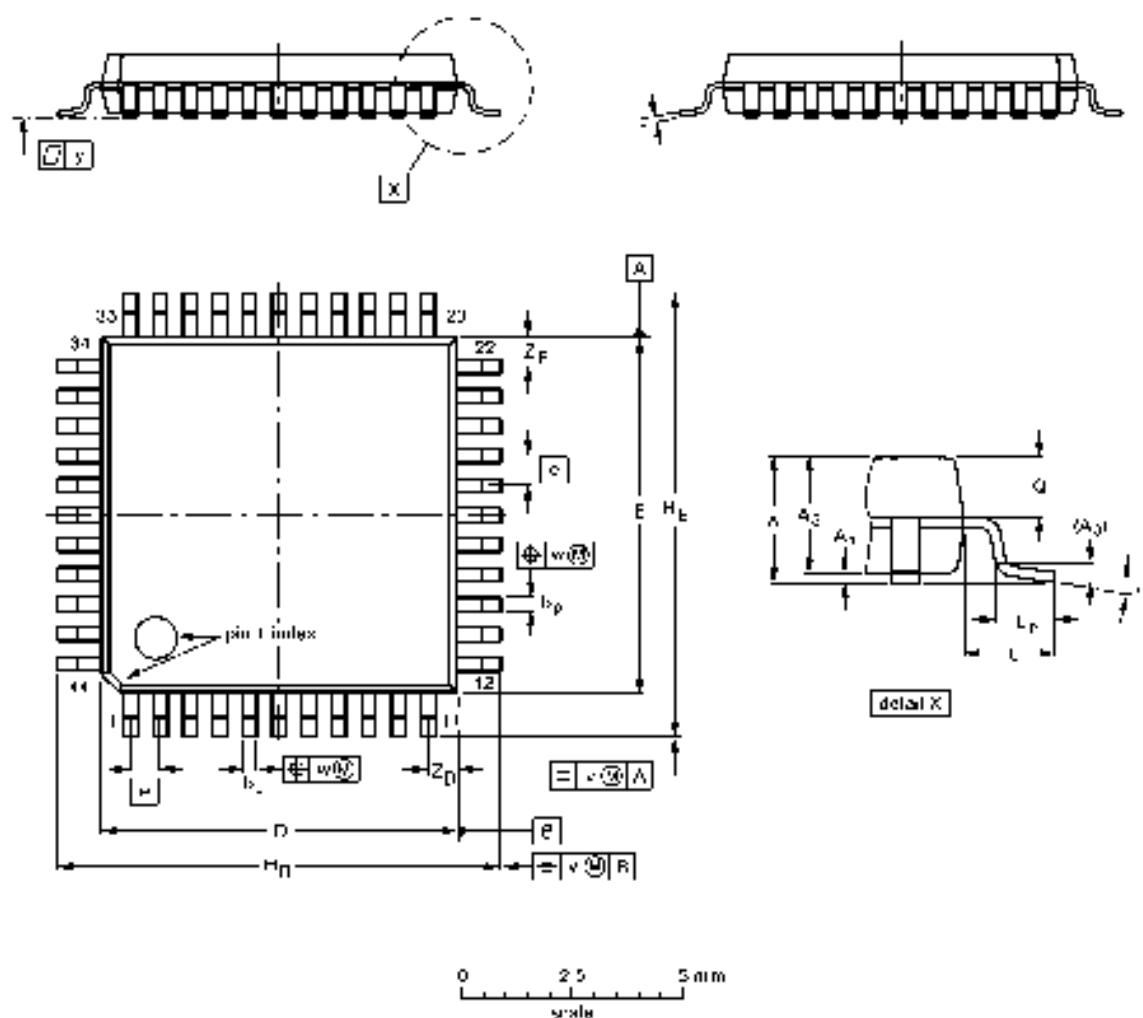
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	ENAJ			
SOT187-2	12E10	MC-047AC				92-11-17 90-02-20

## CMOS single-chip 8-bit microcontrollers

80C652/83C652

**QFP44: plastic quad flat package; 44 leads (lead length 1.3 mm); body 10 x 10 x 1.75 mm**

**SOT307-2**



**DIMENSIONS (mm are the original dimensions)**

UNIT	$A_{max}$	$A_1$	$A_2$	$A_3$	$b_p$	$c$	$D^{(1)}$	$E^{(1)}$	$\epsilon$	$H_D$	$H_E$	$L$	$L_p$	$Q$	$q$	$w$	$\gamma$	$Z_D^{(1)}$	$Z_E^{(1)}$	$\gamma$
mm	2.10	0.80 0.05	1.60 1.65	0.25	0.40 0.20	0.25 0.14	0.1 0.9	0.1 0.9	0.8	12.9 12.5	12.5 12.0	13	0.95 0.55	0.05 0.75	0.15	0.15	0.1	1.2 0.9	1.2 0.9	10° 5°

## Notes

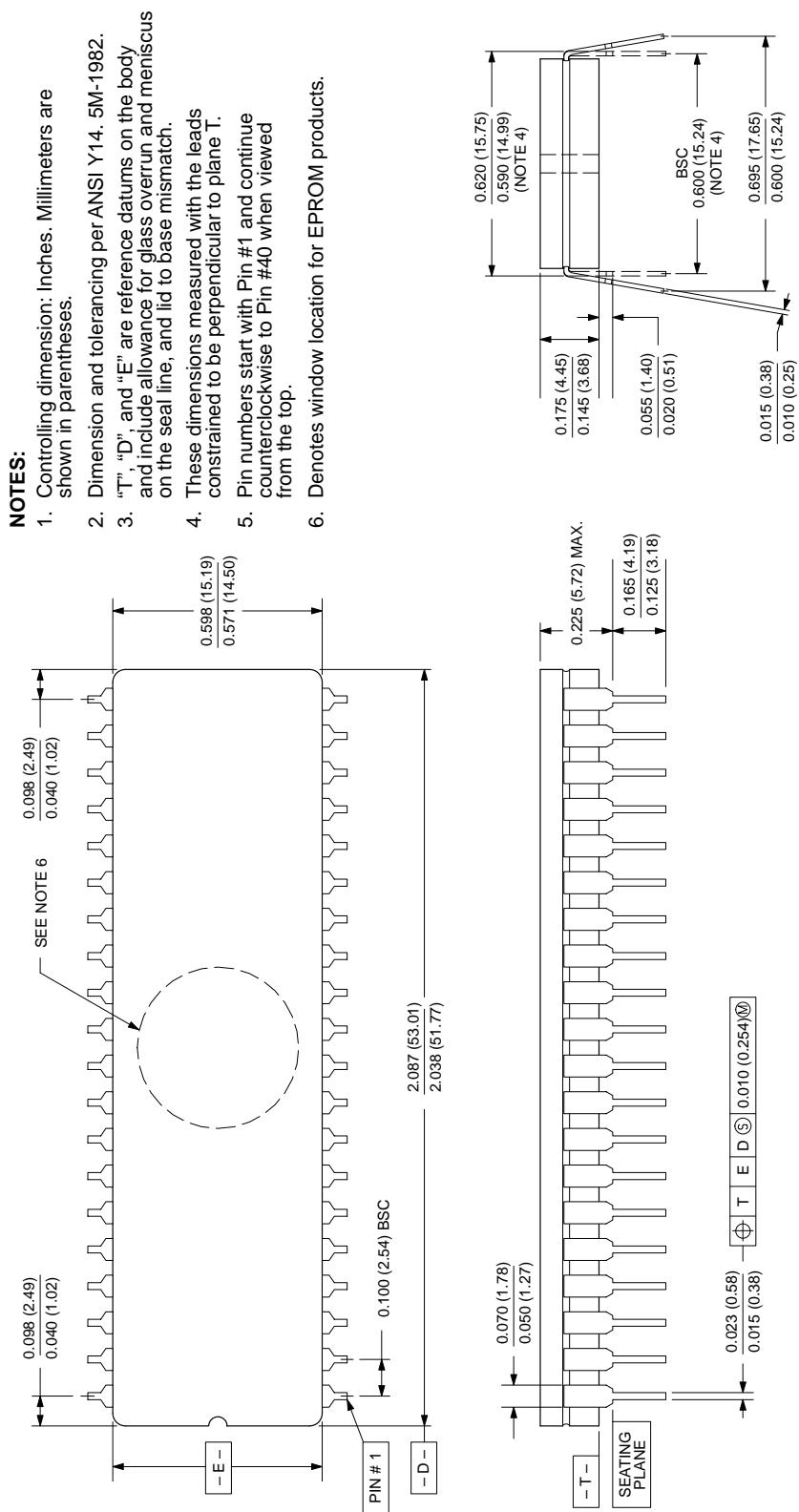
1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
SO1207-2	IEC	JEDEC	EIAJ	 	42-11-17 35-02-04

## CMOS single-chip 8-bit microcontrollers

## 80C652/83C652

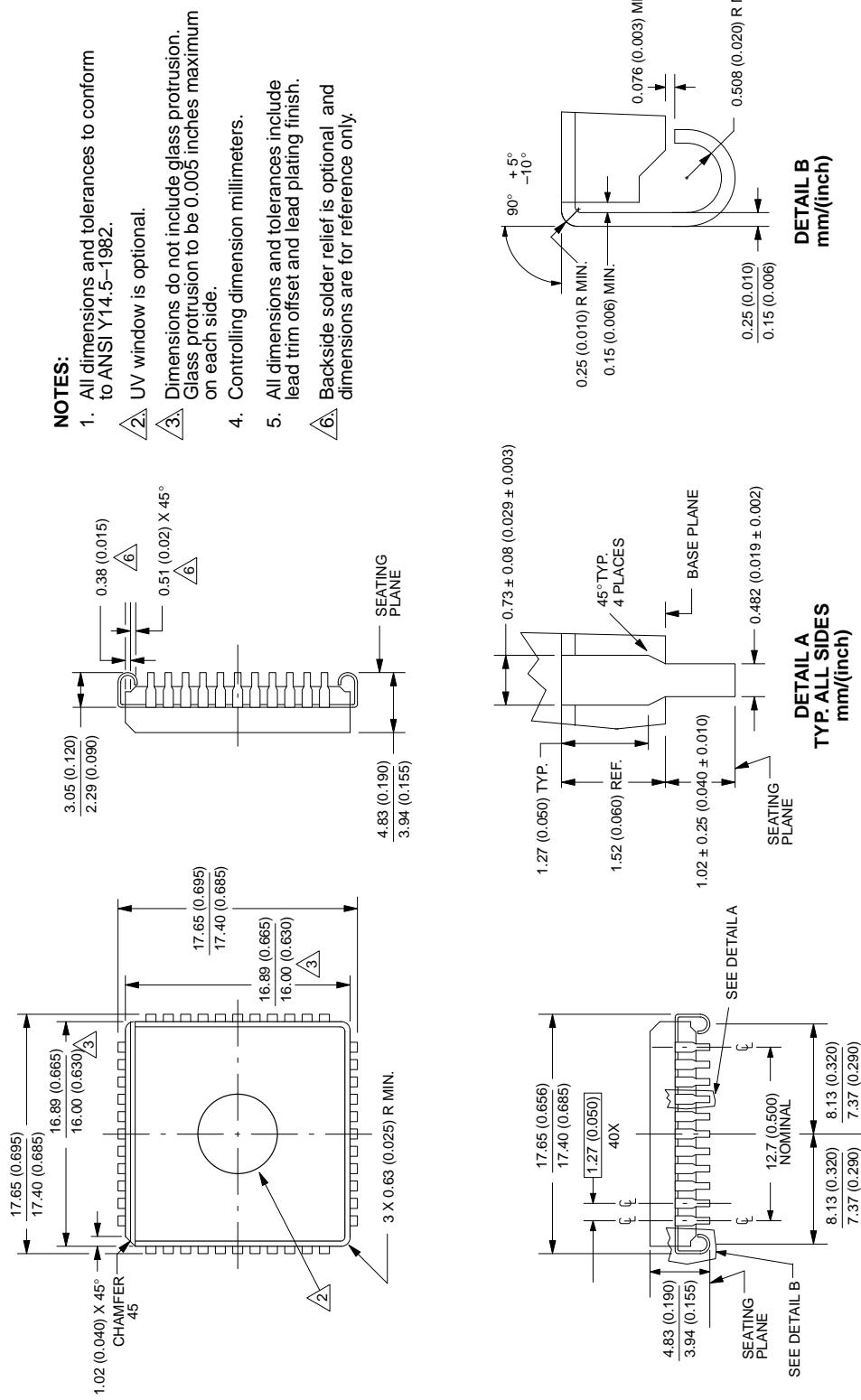
## 0590B 40-PIN (600 mils wide) CERAMIC DUAL IN-LINE (F) PACKAGE (WITH WINDOW (FA) PACKAGE)



## CMOS single-chip 8-bit microcontrollers

80C652/83C652

## 1472A 44-PIN CERQUAD J-BEND (K) PACKAGE



## CMOS single-chip 8-bit microcontrollers

80C652/83C652

## DEFINITIONS

Data Sheet Identification	Product Status	Definition
<i>Objective Specification</i>	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
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